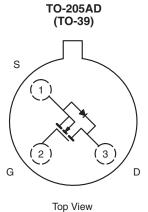
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### N-Channel 90 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	90				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	4				
Configuration	Single				



#### **FEATURES**

- Military Qualified
- Low On-Resistence: 3.6  $\Omega$
- Low Threshold: 1.6 V
- Low Input Capacitance: 35 pF
- Fast Switching Speed: 6 ns
- Low Input and Output Leakage

#### **BENEFITS**

- Guaranteed Reliability
- Low Offset Voltage
- Low-Voltage Operation
- · Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

#### **APPLICATIONS**

- Hi-Rel Systems
- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

ORDERING INFORMATION				
PART	PACKAGE	PACKAGE DESCRIPTION/DSCC PART NUMBER		
2N6661		Commercial	2N6661	
		Commercial, Lead (Pb)-free	2N6661-E3	
2N6661-2		See -2 Flow Document	2N6661-2	
2N6661JANTX TO-205AD (TO-39)	JANTX2N6661 (std Au leads)	2N6661JTX02		
	(TO-39)	JANTX2N6661 (with solder)	2N6661JTXL02	
		JANTX2N6661P (with PIND)	2N6661JTXP02	
2N6661JANTXV		JANTXV2N6661 (std Au leads)	2N6661JTXV02	
		JANTXV2N6661P (with PIND)	2N6661JTVP02	

ABSOLUTE MAXIMUM RATINGS	$T_A = 25  ^{\circ}C$ , unless othe	rwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V <sub>DS</sub>	90	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20	v	
Continuous Drain Current (T <sub>J</sub> = 150 °C)	T <sub>C</sub> = 25 °C	-	0.86		
	T <sub>C</sub> = 100 °C	I <sub>D</sub>	0.54	A	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	3		
Mayimum Dayyar Dissination	T <sub>C</sub> = 25 °C	P <sub>D</sub>	6.25	W	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	FD F	0.725	vv	
Thermal Resistance, Junction-to-Ambient <sup>b</sup>		R <sub>thJA</sub>	170	°C ///	
Thermal Resistance, Junction-to-Case		R <sub>thJC</sub>	20	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

#### Notes

- a. Pulse width limited by maximum junction temperature.
- b. Not required by military spec.



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<b>SPECIFICATIONS</b> (T <sub>A</sub> = 25 °C	C, unless o	otherwise not	ed)						
						LIMITS			
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.b	MAX.	UNIT		
Static									
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{DS}$	$= 0 \text{ V}, I_D = 10$	) μΑ	90	125	-		
		$V_{DS} = V_{GS}$ , $I_D = 1$ mA $T_A = -55$ °C		0.8	1.6	2	V		
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>			T <sub>A</sub> = - 55 °C	-	1.8	2.5	\ \ \	
				T <sub>A</sub> = 125 °C	0.3	1.3	-		
Cata Bady Laglaga	1	V <sub>GS</sub> = ± 20 V	V <sub>DS</sub>	$V_{DS} = 0 V$ - $\pm 100$					
Gate-Body Leakage	ody Leakage $I_{GSS}$ $V_{GS} =$	VGS = ± 20 V		T <sub>A</sub> = 125 °C	-	-	± 500	nA	
Zava Cata Valtaga Dvain Cuwant	1	V <sub>GS</sub> = 0 V	$V_{DS}$	= 72 V	-	-	1		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			T <sub>A</sub> = 125 °C	-	-	100	μΑ	
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	V <sub>DS</sub>	= 10 V	-	1.8	-	mA	
		V <sub>GS</sub> = 5 V	I <sub>D</sub> =	= 0.3 A	-	3.8	5.3		
Drain-Source On-State Resistanceb	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub>	= 1 A	-	3.6	4	Ω	
			V <sub>GS</sub> = 10 V	T <sub>A</sub> = 125 °C <sup>d</sup>	-	6.7	7.5		
Forward Transconductanceb	9 <sub>fs</sub>	V <sub>DS</sub> = 7.5 V, I <sub>D</sub> = 0.475 A		170	340	-	mS		
Diode Forward Voltage	$V_{SD}$	V <sub>GS</sub> = 0 V	I <sub>S</sub> =	0.86 A	0.7	0.9	1.4	V	
Dynamic	<u>'</u>					'	<b>,</b>	,	
Input Capacitance	C <sub>iss</sub>				-	35	50		
Output Capacitance	Coss	$V_{GS} = 0 \text{ V}$ $V_{DS} = 25 \text{ V}$		\/ f _ 1 \/ LI¬	-	15	40		
Reverse Transfer Capacitance	C <sub>rss</sub>	$V_{GS} = 0 V$ $V_{DS} = 25 V$ , $f = 1 MHz$	-	2	10	pF			
Drain-Source Capacitance	C <sub>ds</sub>	1			-	30	-		
Switching <sup>c</sup>									
Turn-On Time	t <sub>ON</sub>	V <sub>DD</sub> :	= 25 V, R <sub>L</sub> = 3	23 Ω	-	6	10	20	
Turn-Off Time	t <sub>OFF</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 23 \Omega$		$R_g = 23 \Omega$	-	8	10	ns	

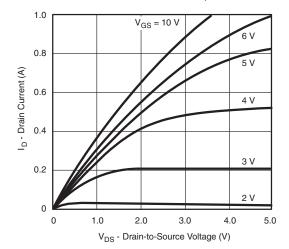
#### Notes

- a. FOR DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW  $\leq$  300  $\mu$ s duty cycle  $\leq$  2 %.
- c. Switching time is essentially independent of operating temperature.
- d. This parameter not registered with JEDEC.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

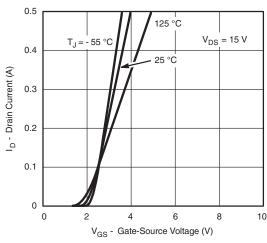
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## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

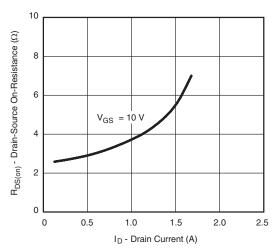


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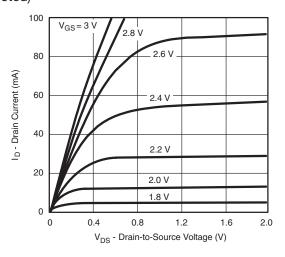
#### **Ohmic Region Characteristics**



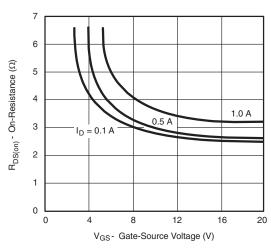
#### **Transfer Characteristics**



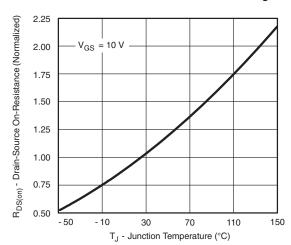
On-Resistance vs. Drain Current



#### **Output Characteristics for Low Gate Drive**



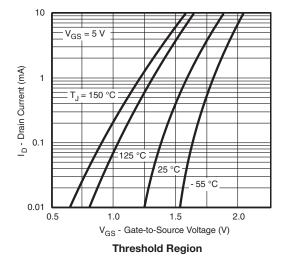
#### On-Resistance vs. Gate-to-Source Voltage



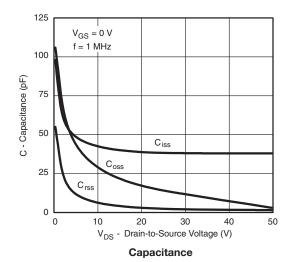
Normalized On-Resistance vs. Junction Temperature

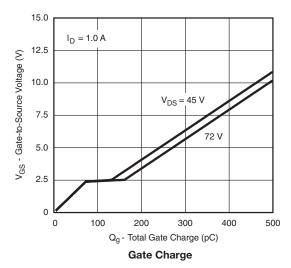
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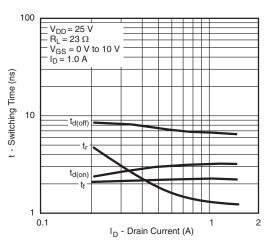
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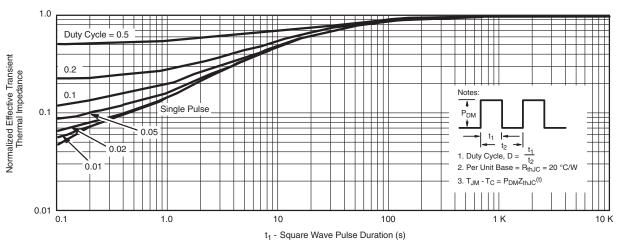


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Load Condition Effects on Switching

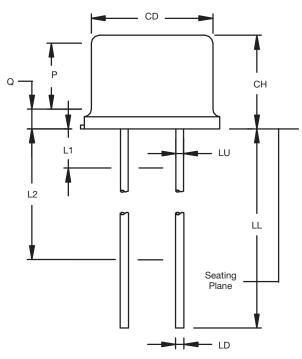
Normalized Thermal Transient Impedance, Junction-to-Ambient

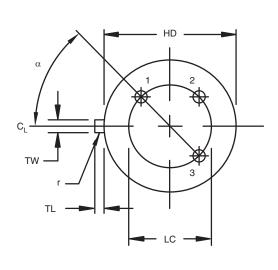
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### **TO-205AD (TO-39 TALL LID)**





DIM.	INC	IES	MILLIN	IETERS
	MIN.	MAX.	MIN.	MAX.
CD	0.305	0.335	7.75	8.51
CH	0.240	0.260	6.10	6.60
HD	0.335	0.370	8.51	9.40
LC <sup>(6)</sup>	0.200	) TP	5.08	3 TP
LD <sup>(7)(8)</sup>	0.016	0.021	0.41	0.53
LL (7)(8)	0.500	0.750	12.70	19.05
LU (7)(8)	0.016	0.019	0.41	0.48
L1 <sup>(7)(8)</sup>	_	0.050	_	1.27
L2 (7)(8)	0.250	_	6.35	
P <sup>(5)</sup>	0.100	_	2.54 —	
Q <sup>(4)</sup>	_	0.050	- 1.2	
r <sup>(9)</sup>	_	0.010	- 0.29	
TL <sup>(3)</sup>	0.029	0.045	0.74	1.14
TW <sup>(2)</sup>	0.028	0.034	0.71	0.86
α (6)	45°	TP	45°	TP

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DWG: 5511

#### Notes

- (1) Dimensions are in inches. Metric equivalents are given for general information only.
- (2) Beyond radius (r) maximum, TW shall be held for a minimum length of 0.011" (0.028 mm).
- (3) Dimension TL measured from maximum HD.
- (4) Outline in this zone is not controlled.
- (5) Dimension CD shall not vary more than 0.010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
- (6) Leads at guage plane 0.054" + 0.001", 0.000" (1.37 mm + 0.03 mm, 0.00 mm) below seating plane shall be within 0.007" (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- (7) LU applies between L1 and L2, LD applies between L2 and L maximum. Diameter is uncontrolled in L1 and beyond LL minimum.
- (8) All three leads.
- (9) Radius (r) applies to both inside corners of tab.
- (10) Drain is electrically connected to the case.

Revison: 27-Jul-15 1 Document Number: 71367



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